

To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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Phase-out/Discontinued

**SWITCHING
P-CHANNEL MOS FET
INDUSTRIAL USE**

DESCRIPTION

This product is P-Channel MOS Field Effect Transistor designed for DC/DC converter and power management applications of notebook computers.

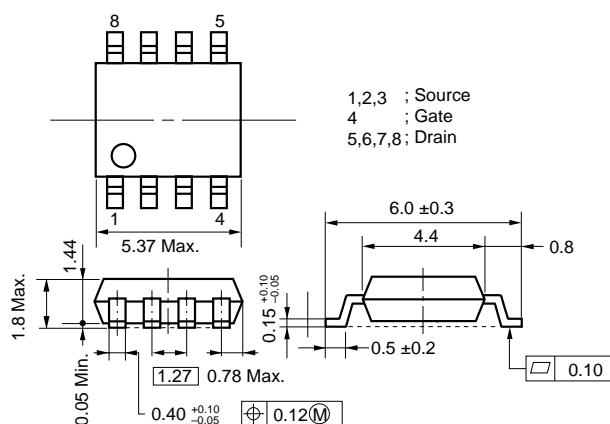
FEATURES

- Low on-resistance
 $R_{DS(on)1} = 70 \text{ m}\Omega$ (MAX.) ($V_{GS} = -10 \text{ V}$, $I_D = -2.5 \text{ A}$)
 $R_{DS(on)2} = 160 \text{ m}\Omega$ (MAX.) ($V_{GS} = -4 \text{ V}$, $I_D = -2.0 \text{ A}$)
- Low C_{iss} : $C_{iss} = 840 \text{ pF}$ (TYP.)
- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

ORDERING INFORMATION

PART NUMBER	PACKAGE
μ PA1710AG	Power SOP8

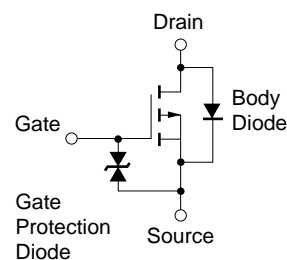
PACKAGE DRAWING (Unit : mm)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, All terminals are connected.)

Drain to Source Voltage ($V_{GS} = 0 \text{ V}$)	V_{DSS}	-30	V
Gate to Source Voltage ($V_{DS} = 0 \text{ V}$)	V_{GSS}	±20	V
Drain Current (DC)	$I_{D(DC)}$	±5.0	A
Drain Current (pulse) ^{Note1}	$I_{D(pulse)}$	±20	A
Total Power Dissipation ($T_A = 25^\circ\text{C}$) ^{Note2}	P_T	2.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	-55 to + 150	°C

EQUIVALENT CIRCUIT



- Notes 1.** $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1 \%$
2. Mounted on ceramic substrate of $1200 \text{ mm}^2 \times 1.1 \text{ mm}$

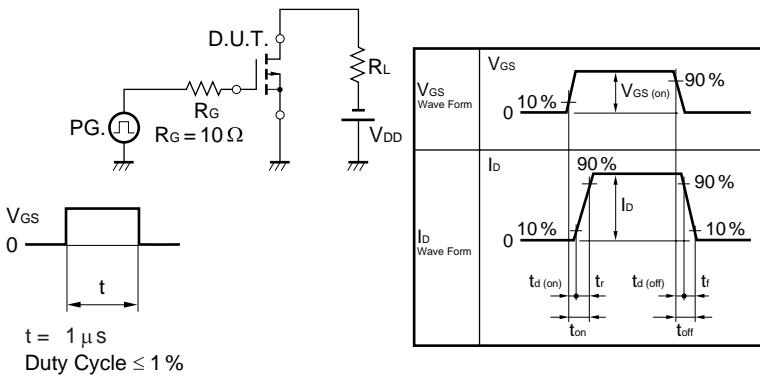
Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

The information in this document is subject to change without notice.

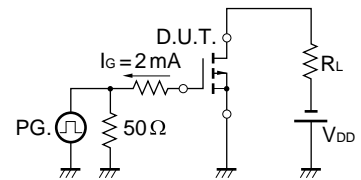
ELECTRICAL CHARACTERISTICS (T_A = 25 °C, All terminals are connected.)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	R _{DS(on)1}	V _{GS} = -10 V, I _D = -2.5 A		45	70	mΩ
	R _{DS(on)2}	V _{GS} = -4 V, I _D = -2.0 A		91	160	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = -10 V, I _D = -1 mA	-1.0	-1.8	-2.5	V
Forward Transfer Admittance	y _{fs}	V _{DS} = -10 V, I _D = -2.5 A	3.0	5.6		S
Drain Leakage Current	I _{DSS}	V _{DS} = -30 V, V _{GS} = 0 V			-10	μA
Gate to Source Leakage Current	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μA
Input Capacitance	C _{iss}	V _{DS} = -10 V		840		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V		570		pF
Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		190		pF
Turn-on Delay Time	t _{d(on)}	I _D = -2.5 A		13		ns
Rise Time	t _r	V _{GS(on)} = -10 V		66		ns
Turn-off Delay Time	t _{d(off)}	V _{DD} = -15 V		82		ns
Fall Time	t _f	R _G = 10 Ω		52		ns
Total Gate Charge	Q _G	I _D = -5.0 A		27.3		nC
Gate to Source Charge	Q _{GS}	V _{DD} = -24 V		2.7		nC
Gate to Drain Charge	Q _{GD}	V _{GS} = -10 V		8.2		nC
Body Diode Forward Voltage	V _{F(S-D)}	I _F = 5.0 A, V _{GS} = 0 V		0.81		V
Reverse Recovery Time	t _{rr}	I _F = 5.0 A, V _{GS} = 0 V		61		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 50 A/μs		71		nC

TEST CIRCUIT 1 SWITCHING TIME

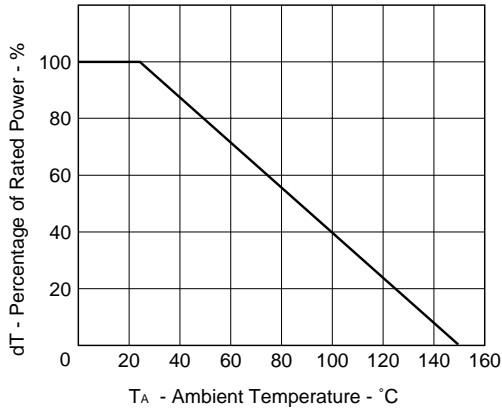


TEST CIRCUIT 2 GATE CHARGE

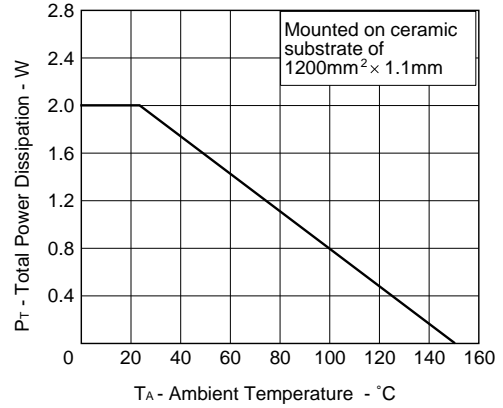


TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

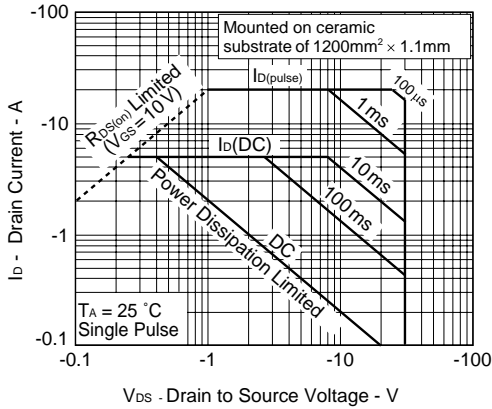
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



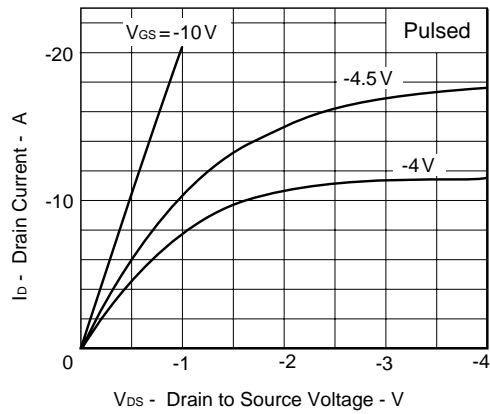
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



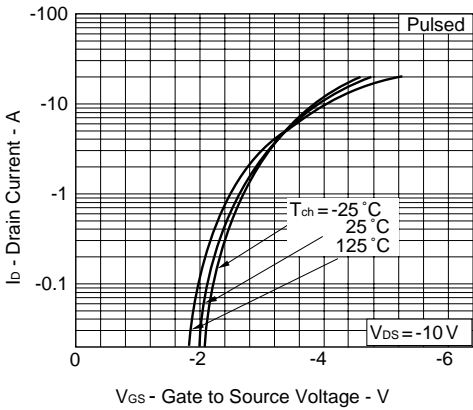
FORWARD BIAS SAFE OPERATING AREA



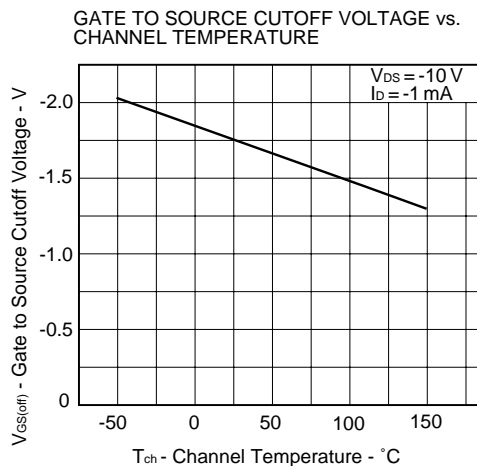
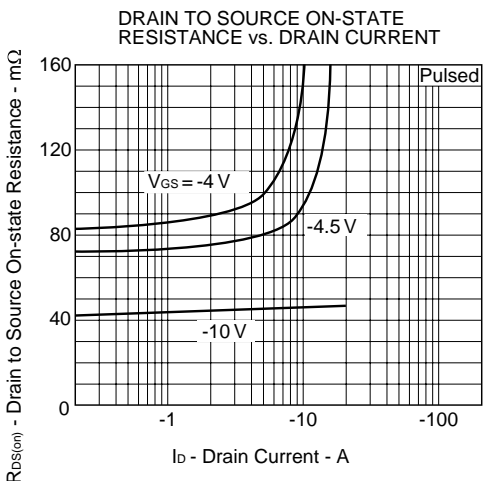
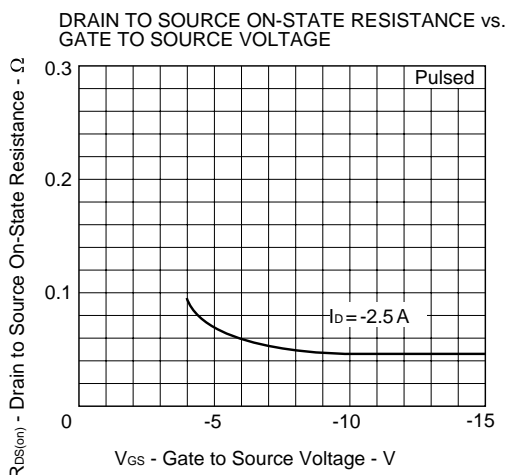
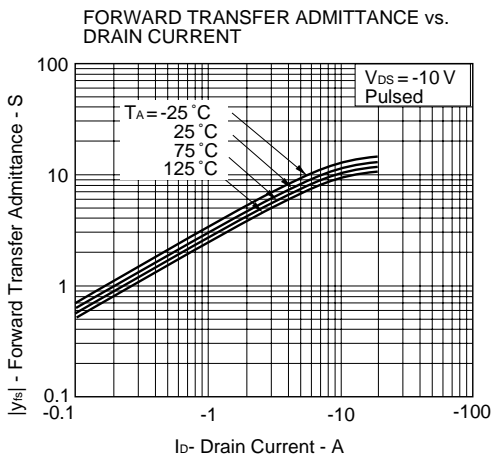
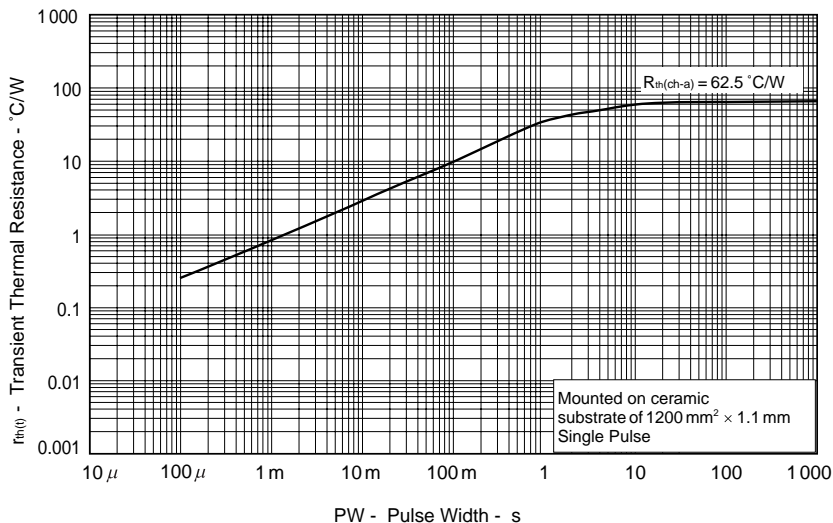
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

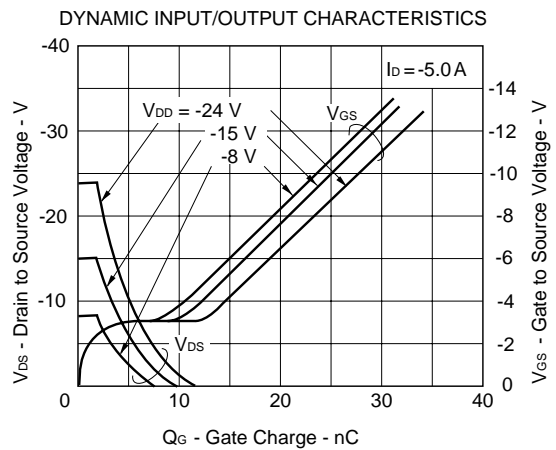
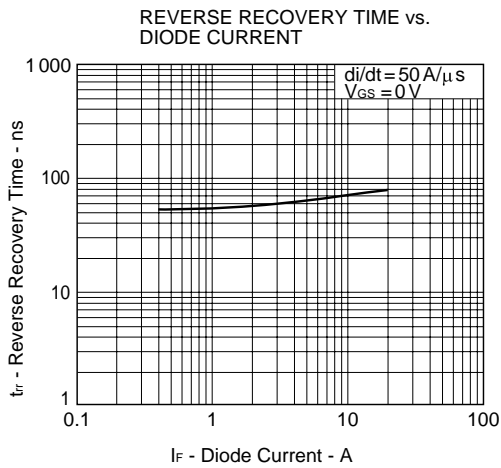
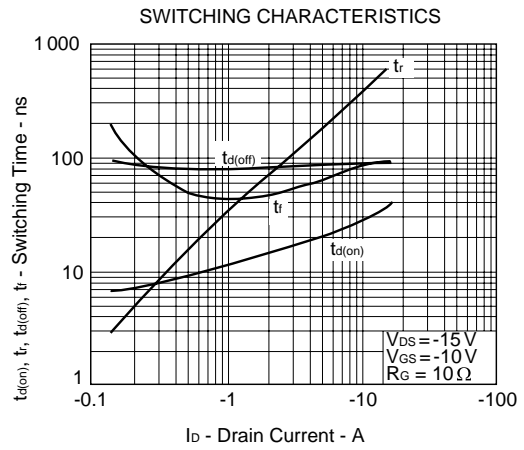
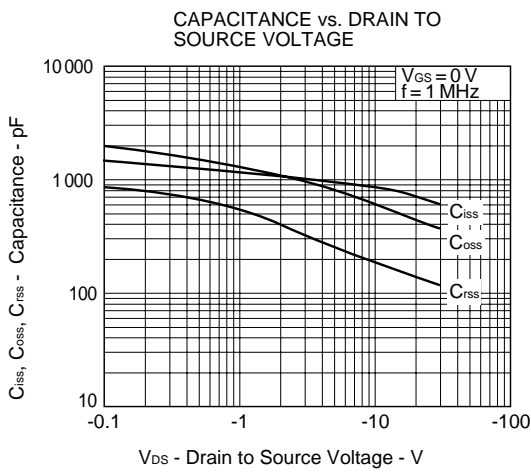
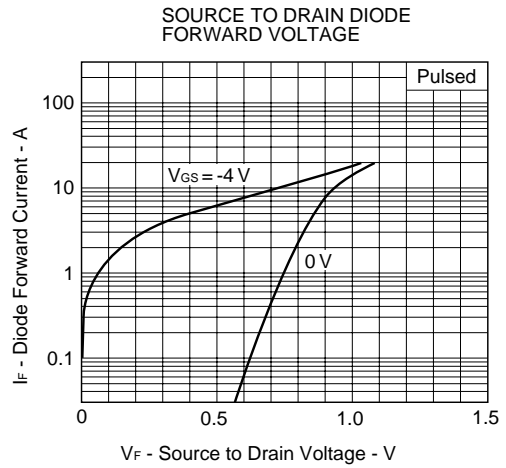
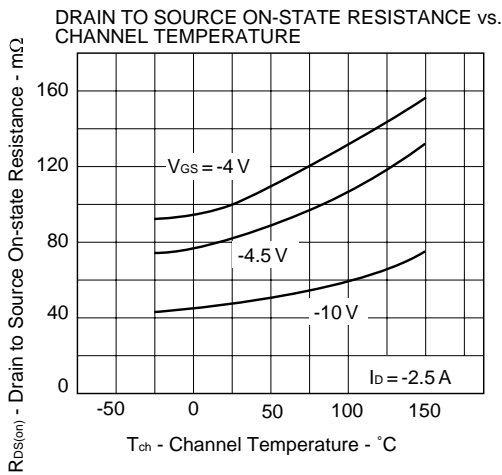


FORWARD TRANSFER CHARACTERISTICS



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH





[MEMO]

[MEMO]

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Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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